



74LVC32A

QUADRUPLE 2-INPUT OR GATES

Description

The 74LVC32A provides four independent 2-input OR gates. The device is designed for operation with a power supply range of 1.65V to 3.6V. The inputs are tolerant to 5.5V allowing this device to be used in a mixed-voltage environment. The device is fully specified for partial power down applications using I_{OFF} . The I_{OFF} circuitry disables the output preventing damaging current backflow when the device is powered down.

The gates perform the positive Boolean function:

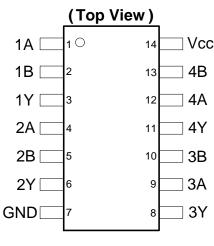
$$Y = A + B \text{ or } Y = \overline{\overline{A} \bullet \overline{B}}$$

Features

Notes:

- Supply Voltage Range from 1.65V to 3.6V
- Sinks 24mA at V_{CC} = 3.3V
- CMOS low power consumption
- IOFF Supports Partial-Power-Down Mode Operation
- Inputs or outputs accept up to 5.5V
- Inputs can be driven by 3.3V or 5.5V allowing for voltage translation applications.
- ESD Protection Exceeds JESD 22
 - 200-V Machine Model (A115)
 - 2000-V Human Body Model (A114)
- Latch-Up Exceeds 250mA per JESD 78, Class I
- Range of Package Options SO-14 and TSSOP-14
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/productdefinitions/</u>

Pin Assignments



SO-14 / TSSOP-14

Applications

- Voltage level shifting
- General-purpose logic
- Power down signal isolation
- Wide array of products such as:
 - PCs, networking, notebooks, ultrabooks, netbooks, PDAs
 - Computer peripherals, hard drives, CD/DVD ROM
 - TV, DVD, DVR, set top boxes

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

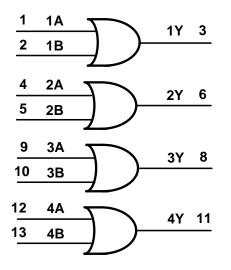
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



Pin Descriptions

Pin Number	Pin Name	Description
1	1A	Data Input
2	1B	Data Input
3	1Y	Data Output
4	2A	Data Input
5	2B	Data Input
6	2Y	Data Output
7	GND	Ground
8	3Y	Data Output
9	ЗA	Data Input
10	3B	Data Input
11	4Y	Data Output
12	4A	Data Input
13	4B	Data Input
14	Vcc	Supply Voltage

Logic Diagram



Function Table

Inp	Inputs		
Α	В	Y	
L	L	L	
L	Н	Н	
н	L	Н	
н	Н	Н	



Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	kV
ESD MM	Machine Model ESD Protection	200	V
V _{CC}	Supply Voltage Range	-0.5 to 6.5	V
VI	Input Voltage Range	-0.5 to 6.5	V
Vo	Voltage applied to output in high impedance or IOFF state	-0.5 to 6.5	V
V _O Voltage applied to output in high or low state		-0.3 to V _{CC} +0.5	V
I _{IK}	Input Clamp Current VI <0	-50	mA
I _{OK}	Output Clamp Current V _O <0	-50	mA
lo	Continuous output current	±50	mA
Icc,, Ignd	Continuous current through V _{CC} or GND	±100	mA
T _J Operating Junction Temperature		-40 to +150	°C
T _{STG}	Storage Temperature	-65 to +150	°C
Ртот	Total Power Dissipation	500	mW

Absolute Maximum Ratings (Note 4) (@T_A = +25°C, unless otherwise specified.)

Note: 4. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

Recommended Operating Conditions (Note 5) (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Max	Unit
Vcc	Supply Voltage	—	1.65	3.6	V
VI	Input Voltage	—	0	5.5	V
λ.	Output Mallana	Active Mode	0	Vcc	V
Vo	Output Voltage	V _{CC} = 0V; Power Down Mode	0	5.5	_
A ± / A > /	han at the solution where on faill and a	V _{CC} = 1.65V to 2.7V	_	20	
Δt/ΔV	Input transition rise or fall rate	V _{CC} = 2.7V to 3.6V	_	10	ns/V
TA	Operating free-air temperature	—	-40	+125	°C

Note: 5. Unused inputs should be held at V_{CC} or Ground.



0	Demonstration	Test Conditions	Vcc	T _A = -40°C	C to +85°C	T _A = -40°C	to +125°C	1114
Symbol	Parameter			Min	Мах	Min	Мах	Unit
		—	1.65V to 1.95V	0.65 X V _{CC}	_	0.65 X V _{CC}	_	
VIH	High-Level Input Voltage	—	2.3V to 2.7V	1.7	_	1.6	_	V
	Vollago	—	2.7 V to 3.6V	2.0	_	2.0	_	
		—	1.65V to 1.95V	_	0.35 X V _{CC}	_	0.35 X V _{CC}	
VIL	Low-Level Input voltage	—	2.3V to 2.7V	—	0.7	—	0.7	V
	i onago	—	2.7V to 3.6V	—	0.8	—	0.8	
		I _{OH} = -100μA	1.65V to 3.6V	V _{CC} – 0.2	—	V _{CC} - 0.3	—	
	High-Level Output Voltage	I _{OH} = -4mA	1.65V	1.2	—	_	—	
N/		I _{OH} = -8mA	2.3V	1.9	—	—	—	v
Vон		1 40 1	2.7V	2.2	—	2.05	—	v
		I _{OH} = -12mA	3.0V	2.3	—	2.1	—	
		I _{OH} = -24mA	3.0V	2.2	—	2.0	—	
		I _{OH} = 100μA	1.65V to 3.6V	—	0.2	—	0.3	
		I _{OH} = 4mA	1.65V	—	0.45	_	0.6	
	Low-Level Output	I _{OH} = 8mA	2.3V	—	0.70	_	0.85	V
V _{OL}	Voltage	1 10	2.7V	—	0.40	—	0.6	v
		I _{ОН} = 12mA	3.0V	—	0.55	_	0.6	
		I _{OH} =-24mA	3.0V	—	0.55	_	0.6	
I _I	Input Current	V _I =GND to 5.5V	3.6V		± 5		± 20	μA
IOFF	Power Down Leakage Current	V_1 or $V_0 = 0V$ to 3.6V	0	—	10	_	20	μA
Icc	Supply Current	$V_I = GND \text{ or } V_{CC} I_O = 0$	3.6V	—	10	—	40	μA
ΔI _{CC}	Additional Supply Current	One input at V _{CC} –0.6V Other at Vcc or Gnd.	2.7V to 3.6V	—	500	_	5000	μA

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)



Switching Characteristics

Symbol	Parameter	Test	V	Т	_A = +25°	С	-40°C to	o +85°C	-40°C to	+125°C	Unit
Symbol P	Farameter	Conditions	V _{cc}	Min	Тур.	Max	Min	Max	Min	Max	Unit
			1.65V to1.95V	1.0	4.2	8.2	1.0	8.7	1.0	10.2	
	Propagation	Figure 2	2.3V to 2.7V	1.0	3.6	4.9	1.0	5.4	1.0	6.9	20
t _{PD}	Delay A _N or B _N to Y _N	Figure 2	2.7V	1.0	3.0	4.6	1.0	4.9	1.0	5.5	ns
	10 1 1		3.V to 3.6V	1.0	2.5	4.1	1.0	4.2	1.0	5.0	
t _{SK(0)}	Output Skew Time	_	3.V to 3.6V	_	_	_	_	1.0	_	1.5	ns

Operating Characteristics (@T_A = +25°C, unless otherwise specified.)

	Parameter	Test	V _{CC} = 1.8V	$V_{CC} = 2.5V$	$V_{CC} = 3.3V$	Unit	
	Falameter	Conditions Typ		Тур	Тур	Onit	
C _{pd}	Power dissipation capacitance per gate	f = 10 MHz	7.4	10.5	12.4	pF	
Cı	Input Capacitance	$V_i = V_{CC} - or$ GND	4	4	4	pF	

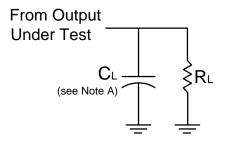
Package Characteristics

Symbol	Parameter	Test Conditions	V _{cc}	Min	Тур	Max	Unit
0	Thermal Resistance	SO-14	(Note 6)	—	TBD	—	°C/W
θ _{JA}	Junction-to-Ambient	TSSOP-14		_	159	_	0/00
0	Thermal Resistance	SO-14	(Note 6)	—	TBD	_	°C/W
$\theta_{\rm JC}$	Junction-to-Case	TSSOP-14	(Note 6)	_	25	_	C/VV

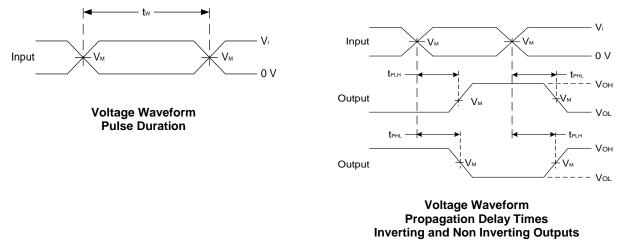
Note: 6. Test condition for SO-14 and TSSOP-14: Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

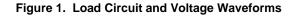


Parameter Measurement Information



Vcc	Inputs		VM	CL	RL
	VI	t _r /t _f			_
1.8V±0.15V	V _{CC}	≤2ns	V _{CC} /2	30pF	1ΚΩ
2.5V±0.2V	V _{CC}	≤2ns	V _{CC} /2	30pF	500Ω
2.7V	2.7V	≤2.5ns	1.5V	50pF	500Ω
3.3V±0.3V	2.7V	≤2.5ns	1.5V	50pF	500Ω

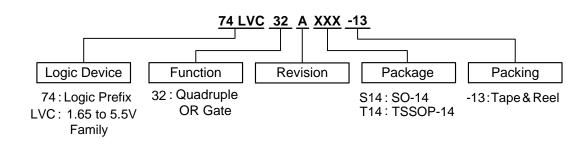




- Notes:
- A. Includes test lead and test apparatus capacitance. B. All pulses are supplied at pulse repetition rate \leq 10 MHz C. Inputs are measured separately one transition per measurement D. t_{PLH} and t_{PHL} are the same as t_{PD}



Ordering Information

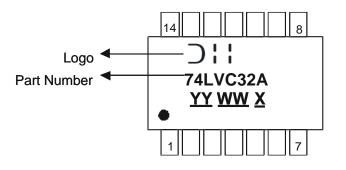


Orderable Part Number	Package	Package		Packing	
Orderable Part Nulliber	Code	(Note 7)	Quantity	Carrier	Part Number Suffix
74LVC32AS14-13	S14	SO-14	2,500	13" Tape & Reel	-13
74LVC32AT14-13	T14	TSSOP-14	2,500	13" Tape & Reel	-13

Note: 7. The taping orientation and tape details can be found at http://www.diodes.com/datasheets/ap02007.pdf

Marking Information

(1) SO-14, TSSOP-14



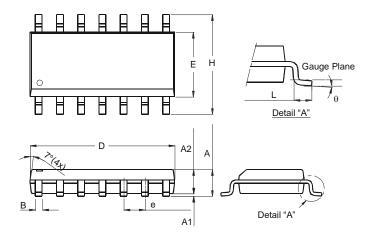
 $\underline{YY} : Year : 08, 09, 10 \sim$ $\underline{WW} : Week : 01 \sim 52; 52$ represents 52 and 53 week $\underline{X} : Internal Code$

Part Number	Package
74LVC32A	SO-14
74LVC32A	TSSOP-14



Package Outline Dimensions (All dimensions in mm.)

Please see http://www.diodes.com/package-outlines.html for the latest version.



	SO-14						
Dim	Min	Max					
Α	1.47	1.73					
A1	0.10	0.25					
A2	1.45	1.45 Typ					
в	0.33	0.51					
D	8.53	8.74					
Е	3.80	3.99					
e	1.27	Тур					
H	5.80	6.20					
L	0.38	1.27					
θ	0°	8°					
All Di	mension	s in mm					

15501-14	
Pin#1 Indent	÷
$ \begin{array}{c} \blacksquare \blacksquare \blacksquare \blacksquare \blacksquare \blacksquare \blacksquare \blacksquare \blacksquare \\ $	

TSSOP-14

TSSOP-14			
Dim	Min	Max	
a1	7° (4X)		
a2	0°	8°	
Α	4.9	5.10	
В	4.30	4.50	
С	-	1.2	
D	0.8	1.05	
F	1.00 Typ		
F1	0.45	0.75	
G	0.65 Typ		
K	0.19	0.30	
Ĺ	6.40 Тур		
All Dimensions in mm			

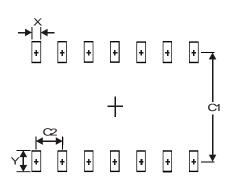
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SO-14



Suggested Pad Layout

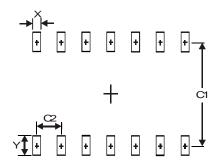
Please see http://www.diodes.com/package-outlines.html for the latest version.



SO-14

Dimensions	Value (in mm)
Х	0.60
Y	1.50
C1	5.4
C2	1.27

TSSOP-14



Dimensions	Value (in mm)
Х	0.45
Y	1.45
C1	5.9
C2	0.65



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